





2.5 mm x 3.2 mm Ceramic Package SMD TCXO

I547/I747 Series

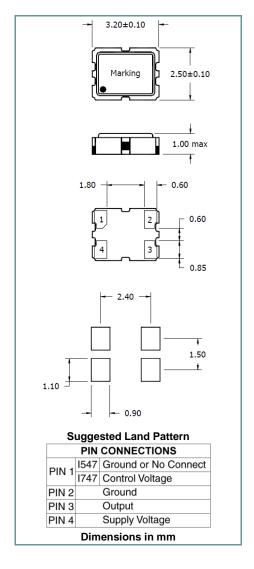
Product Features:

Clipped Sinewave Analog Compensation Available ±0.5ppm Stability RoHS Compliant / Pb-free

Applications:

GPS Smart Meters Wireless Base Stations Sonet / SDH T1/E1, T3/E3

| Frequency | 10MHz to 52MHz | |
|-----------------------------|--|--|
| Frequency Tolerance @ 25° C | ±2.0ppm after second reflow | |
| Frequency Stability | | |
| Vs Temperature | See Part Numbering Guide | |
| Vs Supply Voltage (± 5%) | ±0.2ppm Maximum | |
| Vs Load (10%) | ±0.2ppm Maximum | |
| Output Level | | |
| Clipped Sinewave | 0.8V p-p Minimum | |
| Output Load | | |
| Clipped Sinewave | 10KOhms / 10 pF | |
| Start Time (90% of Vp-p) | 3.0mSec Maximum | |
| Aging | ±1ppm / Year Maximum | |
| Supply Voltage | See Part Numbering Guide, tolerance ± 5% | |
| Current | | |
| <u><</u> 32MHz | 1.5mA Maximum | |
| >32mHz | 2.0mA Maximum | |
| Voltage Control | 1.5Vdc ±1.0Vdc, ± 5.0ppm Minimum (Only for I747) | |
| Operating Temperature Range | See Part Numbering Guide | |
| Storage Temperature Range | -40°C to +85°C | |
| Phase Noise (typical) | -87 dBc/Hz at 10Hz | |
| ,,, | -112 dBc/Hz at 100Hz | |
| | -135 dBc/Hz at 1KHz | |
| | | |
| | -145 dBc/Hz at 10KHz | |



Part Numbering Guide

| Sample Part Number: I547-1Q3-20.000 MHz | | | | | |
|---|-----------------------|-----------------------------------|----------------|--------------|--|
| Package | Operating Temperature | FrequencyStability vs Temperature | Supply Voltage | Frequency | |
| I547 (Clipped Sinewave TCXO) I747 (Clipped Sinewave TCVCXO) | 7 = 0°C to +50°C | *, ** Y = ±0.5ppm | 3 = 3.3V | | |
| | 1 = 0°C to +70°C | *N = ±1.0ppm | 7 = 3.0V | | |
| | 3 = -20°C to +70°C | *O = ±1.5ppm | 8 = 2.8V | | |
| | 5 = -30°C to +85°C | *P = ±2.0ppm | 2 = 2.7V | - 20.000 MHz | |
| | 2 = -40°C to +85°C | Q = ±2.5ppm | 1 = 1.8V | | |
| | | R = ±3.0ppm | | | |
| | | $J = \pm 5.0$ ppm | | | |

** Referenced to the midpoint between minimum and maximum frequency value over Operating Temperature Range.

NOTE: It is recommended that a 0.01µF bypass capacitor be connected between Vdd (Pin 4) and Ground (Pin 2) to minimize power supply noise. It is recommended that an external 0.01µF AC-coupling capacitor be connected to output (Pin 3) of the device.

For the TXCO (I547), it is recommended that Pin 1 should not be left floating but be connected to Ground.

Rev: 12/13/17_M



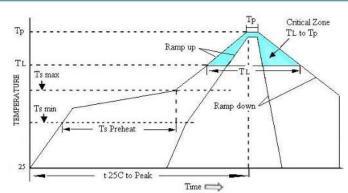




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Pb Free Solder Reflow Profile:



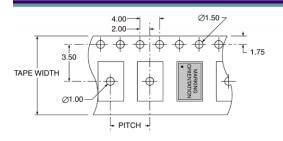
Units are backward compatible with +240°C reflow processes

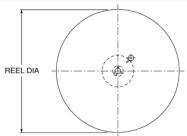
| Ts max to T _L (Ramp-up Rate) | 3°C / second max | |
|---|-------------------|--|
| Preheat | | |
| Temperature min (Ts min) | 150°C | |
| Temperature typ (Ts typ) | 175°C | |
| Temperature max (Ts max) | 200°C | |
| Time (Ts) | 60 to 180 seconds | |
| Ramp-up Tate (T _L to Tp | 3°C / second max | |
| Time Maintained Above | | |
| Temperature (T _L) | 217°C | |
| Time (T _{L)} | 60 to 150 seconds | |
| Book Tomporature (Tp) | 260°C max for 10 | |
| Peak Temperature (Tp) | seconds | |
| Time within 5°C to Peak | 20 to 40 seconds | |
| Temperature (Tp) | 20 to 40 seconds | |
| Ramp-down Rate | 6°C / second max | |
| Tune 25°C to Peak Temperature | 8 minutes max | |

Package Information:

MSL = 1 (package does not contain plastic, storage life is unlimited under normal room conditions) Termination = e4 (Au over Ni over W base metallization)

Tape and Reel Information:





| PITCH | 4.00 |
|--------------|-------|
| TAPE WIDTH | 8.00 |
| REEL DIA | 180 |
| QTY PER REEL | 3,000 |

Tape and Reel Information:

| Thermal Shock | MIL-STD-883, Method 1011, Condition A |
|------------------------------|---|
| Moisture Resistance | MIL-STD-883, Method 1004 |
| Mechanical Shock | MIL-STD-883, Method 2002, Condition B |
| Mechanical Vibration | MIL-STD-883, Method 2007, Condition A |
| Resistance to Soldering Heat | J-STD-020C, Table 5-2 Pb-free devices (except 2 cycles max) |
| Hazardous Substance | Pb-Free / RoHS Compliant |
| Solderability | JESD22-B102 Method 2 (Preconditioning E) |
| Terminal Strength | MIL-STD-883, Method 2004, Test Condition D |
| Gross Leak | MIL-STD-883, Method 1014, Condition C |
| Fine Leak | MIL-STD-883, Method 1014, Condition A2, R1=2x10-8 atm cc/s |
| Solvent Resistance | MIL-STD-202, Method 215 |

Marking:

Line 1: I-Date Code (YWW)

Line 2: Frequency

QUALITY SYSTEM CERTIFIED = ISO 9001 = Rev: 12/13/17_M